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# INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Sheet 1 of 1

| Complete If Known | |
|---|---|
| Application Number | ~~To Be Assigned~~ 10/581797 |
| Filing Date | June 2, 2006 |
| First Named Inventor | Yang YANG *et al.* |
| Art Unit | ~~To Be Assigned~~ 2818 |
| Examiner Name | ~~To Be Assigned~~ Long Tran |
| Attorney Docket Number | 58086-231274 |

## U.S. PATENT DOCUMENTS

| Examiner Initials* | Cite No.[1] | Document Number Number-Kind Code[2] (if known) | Publication Date MM-DD-YYYY | Name of Patentee or Applicant of Cited Document | Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear |
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| | AD | | | | |
| | AE | | | | |
| | AF | | | | |
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| | BA | | | | | |
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| Examiner Signature | /Long Tran/ | Date Considered | 12/16/2007 |
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| First Named Inventor | Yang Yang |
| Art Unit | 2818 |
| Examiner Name | ~~Not Yet Assigned~~ Long Tran |
| Attorney Docket Number | 58086-231274 |

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Sheet 1 of 6

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| Application Number | 10/581,797 – Conf. # 4944 |
| Filing Date | June 2, 2006 |
| First Named Inventor | Yang Yang |
| Art Unit | 2818 |
| Examiner Name | Long K. Tran |
| Attorney Docket Number | 58086-231274 |

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| Examiner Signature | /Long Tran/ | Date Considered | 12/16/2007 |
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Sheet 2 of 6

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| Filing Date | June 2, 2006 |
| First Named Inventor | Yang Yang |
| Art Unit | 2818 |
| Examiner Name | Long K. Tran |
| Attorney Docket Number | 58086-231274 |

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| Examiner Signature | /Long Tran/ | Date Considered | 12/16/2007 |
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| | | | | Filing Date | June 2, 2006 |
| | | | | First Named Inventor | Yang Yang |
| *(Use as many sheets as necessary)* | | | | Art Unit | 2818 |
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| Sheet | 3 | of | 6 | Attorney Docket Number | 58086-231274 |

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| Examiner Signature | /Long Tran/ | Date Considered | 12/16/2007 |
|---|---|---|---|

Used in Lieu of PTO/SB/08A/B
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| Substitute for form 1449/PTO | | | | Complete If Known | |
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| **INFORMATION DISCLOSURE STATEMENT BY APPLICANT** | | | | Application Number | 10/581,797 – Conf. # 4944 |
| | | | | Filing Date | June 2, 2006 |
| | | | | First Named Inventor | Yang Yang |
| *(Use as many sheets as necessary)* | | | | Art Unit | 2818 |
| | | | | Examiner Name | Long K. Tran |
| Sheet | 5 | of | 6 | Attorney Docket Number | 58086-231274 |

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| Examiner Signature | /Long Tran/ | Date Considered | 12/16/2007 |
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| Sheet | 6 | of | 6 |
|---|---|---|---|

| *Complete if Known* | |
|---|---|
| Application Number | 10/581,797 – Conf. # 4944 |
| Filing Date | June 2, 2006 |
| First Named Inventor | Yang Yang |
| Art Unit | 2818 |
| Examiner Name | Long K. Tran |
| Attorney Docket Number | 58086-231274 |

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|---|---|---|---|
| /LT/ | C77 | MARTIN, NAZARIO et al., "Evidence for Two Separate One-electron Transfer Events in Excited Fulleropyrrolidine Dyads Containing Tetrathiafulvalene (TTF)", *J. Phys. Chem.* A 2000, 104, p. 4648-4657. | |

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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